
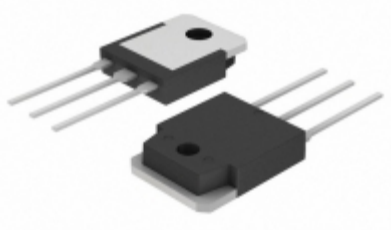



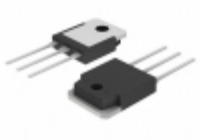
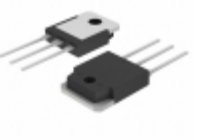
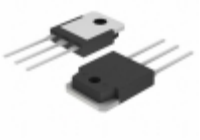
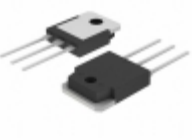
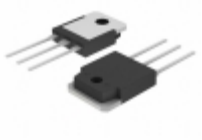
	<h2 style="color: red;">FQA12P20</h2>
	<p><b>Hersteller-Teilenummer:</b> FQA12P20</p> <hr/> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 200V 12.6A TO-3P</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQA12P20.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 2697 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQA12P20
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 200V 12.6A TO-3P
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	2697 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	150W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12.6A (Tc)
Rds On (Max) @ Id, Vgs	470 mOhm @ 6.3A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 25V
Verpackung	Tube

FQA12P20 ist neu im Original. Suche FQA12P20 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA12P20 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQA12P20: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQA12N60C</b> Original FQA12N60C Original</p>	 <p><b>FQA11N90C_F109</b> Fairchild/ON Semiconductor FQA11N90C_F109 Fairchild/ON Semiconductor</p>	 <p><b>FQA13N50C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13.5A TO-3P</p>	 <p><b>FQA11N90_F109</b> Fairchild/ON Semiconductor FQA11N90_F109 Fairchild/ON Semiconductor</p>
 <p><b>FQA13N50</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13.4A TO-3P</p>	 <p><b>FQA12N60</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 12A TO-3P</p>	 <p><b>FQA13N50</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 13.4A TO-3P</p>	 <p><b>FQA12N60</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A TO-3P</p>

### heiße Teile

Mehr

FQA10N60C	FQA10N60C	FQA10N80C	FQA10N80C	FQA10N80C_F109
FQA11N90	FQA11N90	FQA11N90C	FQA11N90C	FQA11N90C
FQA11N90C_F109	FQA11N90_F109	FQA12N60C	FQA12P20	FQA13N50
FQA13N50	FQA13N50C	FQA13N50C	FQA13N50C_F109	FQA13N80
FQA13N80	FQA13N80_F109	FQA140N10	FQA140N10	FQA14N30
FQA14N30	FQA160N08	FQA160N08	FQA16N50	FQA16N50
FQA170N06	FQA170N06	FQA18N40	FQA18N50	FQA19N20C
FQA19N20C	FQA19N20L	FQA19N20L	FQA19N60	FQA19N60
FQA20N40	FQA20N40	FQA20N50	FQA20N60	FQA20N80
FQA24N50	FQA24N50	FQA24N50F	FQA24N50F	FQA24N60

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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